

Contents lists available at ScienceDirect

Journal of Crystal Growth

journal homepage: www.elsevier.com/locate/jcrysgro



Distribution of oxidation states of Cr ions in Ca or Ca/Mg co-doped Cr:Y₃Al₅O₁₂ single-crystal fibers with nitrogen or oxygen annealing environments

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ARTICLE INFO

Article history: Received 22 November 2007 Accepted 14 February 2008 Communicated by R.S. Feigelson Available online 2 March 2008

42.62.Fi 42.70.Hj 42.72.Ai 71.70.Ch

PACS:

Keywords:

A1. Doping A1. Optical microscopy

A2. Laser heated pedestal growth

ABSTRACT

The valence states of Cr ions in Ca or Ca/Mg co-doped Cr:Y₃Al₅O₁₂ (YAG) single-crystal fibers are studied. The fibers were grown using the laser-heated pedestal growth method, followed by annealing treatments up to 1500 °C. The concentrations of the $\rm Cr^{3+}$ and $\rm Cr^{4+}$ ions in octahedral and tetrahedral sites in oxygen or nitrogen environments were characterized. Above 700 °C, migration of $\rm Cr^{4+}$ between octahedral and tetrahedral sites takes place; its relative stabilization energy was estimated. For Ca,Cr:YAG annealed in an oxygen or nitrogen environment, it was 0.25 and 0.3 eV, respectively. For Mg,Ca,Cr:YAG annealed in oxygen or nitrogen, it was 0.47 and 0.49 eV, respectively. For the Ca,Cr:YAG crystal fiber (Ca/Cr = 113.1%) with oxygen annealing, about 35% and 2.5% of Ca ions took part in charge compensation for $\rm Cr^{4+}$ in the octahedral and tetrahedral sites, respectively. The density of oxygen vacancies depends on the concentration of Ca ions. The estimated ratios of the unreacted oxygen vacancies to total oxygen vacancies were about 63% and 88% for oxygen and nitrogen annealing, respectively. The main limitation on the concentration of $\rm Cr^{4+}$ in the tetrahedral site of YAG is the presence of unreacted oxygen vacancies.

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1. Introduction

There has been intense interest in the spectroscopy of Cr^{4+} in tetrahedrally coordinated environments since room-temperature laser operation of $Cr:Y_3Al_5O_{12}$ (YAG) was demonstrated [1]. $Cr^{4+}:YAG$ emission is in the near-infrared (NIR) from 1.2 to 1.6 μ m, and may have applications in tunable and mode-locked solid-state lasers [2–6] and as super-broadband amplified spontaneous emission (ASE) in optical fiber communications [7,8]. When Cr and divalent ions (Ca, Mg) are introduced into YAG, there exist several Cr ion valence states. Cr^{3+} is the dominant species, one which is rarely found in tetrahedrally coordinated sites [7,9] and this is substituted into the octahedral Al site, denoted as Cr^{3+}_{oct} . It is the most stable valence state of the Cr ion, and its crystal field stabilization energy is the largest. At high-temperature oxygen atmosphere with charge compensator, the Cr^{4+} tends to be substituted into the tetrahedral Al site, and is denoted as Cr^{4+}_{ter}

[10-13]. The garnets co-activated with chromium and divalent ions were shown to have Cr4+ ions present both in tetrahedral and in octahedral positions [14]. It was found that irradiation of crystals prepared under reducing conditions forms color centers, with Cr^{4+} ions in octahedral positions (Cr^{4+}_{oct}) having absorption in the UV and visible wavelength range. Oxidization and annealing form centers with Cr4+ at tetrahedral sites, which show strong absorption in 1-1.2 μm wavelength range [15]. It was shown that the electronic recharging and charging processes $Cr_{oct}^{4+} \leftrightarrow Cr_{oct}^{3+}$ taking place in the octahedral sites of the garnet lattice have lower activation energies compared to the chromium migration process $Cr_{tetr}^{4+} \leftrightarrow Cr_{oct}^{4+}$ taking place at higher temperatures or with longer exposures [16]. The ratio $Cr_{tetr}^{4+}/Cr_{oct}^{4+}$ is about 4% at 1700 K and the relative stabilization energy E_{CrAl} was found to be 0.11 eV [17]. Oxygen vacancies can also contribute to the charge compensation [13,18,19]. It is desirable to develop crystal-growth techniques to obtain high concentrations of these lasing centers.

The laser-heated pedestal growth (LHPG) method is fast, economical, flexible, and provides easy adjustment of growth conditions and dopant concentrations. It has been developed to pull Cr⁴⁺:YAG crystal fibers to be used for generating several

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milli-watts of amplified spontaneous emission [7]. In this paper, using an electron gun to deposit MgO on the outside of the Ca,Cr:YAG crystal fiber and with post-growth oxygen and nitrogen annealing treatments, we have characterized the concentrations of Cr in various oxidation states, and analyzed Cr valence changes. The relative stabilization energy for the transformation from Cr_{oct} to Cr_{tetr} as well as the relationship between the concentrations of the charge compensators (Ca²⁺, Mg²⁺), Cr_{oct} Cr_{oct} Cr_{tetr} oxygen vacancies and total Cr have been determined. The efficiency of charge compensation is also analyzed. This paper presents, for the first time, a detailed and quantitative analysis of the Cr⁴⁺ charge compensation efficiency with divalent co-doping.

2. Experimental procedure

2.1. Sample preparation

The Ca,Cr:YAG crystal fibers were prepared by the LHPG method. The source rods were Ca co-doped Cr:YAG with cross section $500\,\mu m \times 500\,\mu m$ and crystal orientation $\langle\,111\,\rangle$. They were first grown at a speed of $24\,mm/min$ with a CO $_2$ laser power of $6.5\,W$ to create fibers of $290\,\mu m$ in diameter. After cutting into $4\,cm$ long pieces, they were placed in an electron gun chamber with an axially rotated mount for side deposition. The chamber temperature was set to $300\,^{\circ}C$ and the electron gun voltage to $6.5\,kV$. MgO was then deposited on the circumference of the Ca,Cr:YAG crystal fiber. After side deposition, the Cr:YAG crystal fibers ions co-doped with divalent ions were re-grown with 1.1-W CO $_2$ laser power at a speed of $2\,mm/min$ to produce $70\,\mu m$ diameter crystal fibers. Post-growth thermal annealing was performed at various temperatures in 1 atm of oxygen or nitrogen for $4\,h$.

2.2. Composition and fluorescence measurements

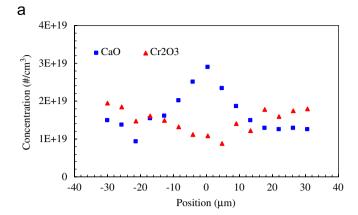
The composition of the crystal fibers was measured by an electron probe micro-analyzer (EPMA, JEOL JXA-8900R). The composition and doping profiles were scanned across the fiber cross-section. The concentrations of Ca^{2+} and Cr ions in the Ca,Cr:YAG fiber were 1.68×10^{19} and $1.49\times 10^{19}\,\text{\#/cm}^3$ while $[\text{Ca}^{2+}\text{+Mg}^{2+}]$ and Cr in the Mg,Ca,Cr:YAG fiber were 3.91×10^{19} and $1.55\times 10^{19}\,\text{\#/cm}^3$, respectively. The concentrations of Ca^{2+} and Cr ions had contrasting distribution profiles as depicted in Fig. 1(a). It has been shown that both Ca^{2+} and Mg^{2+} accumulate near the fiber center, while the concentration of Cr ions is lower at the fiber center compared to the fiber perimeter [18]. The underlining physics is related to the segregation coefficients of Ca^{2+} , Mg^{2+} and Cr^{3+} in YAG crystals.

The EPMA measurement, however, cannot distinguish the oxidation states. Laser scanning confocal microscopy (LSCM) was employed to identify $\rm Cr_{oct}^{3+}$ and $\rm Cr_{tetr}^{4+}$ ions, by excitation with a 532 nm frequency doubled Nd:YAG laser and a 1064 nm Yb-doped fiber laser, respectively. An objective lens with a numerical aperture of 0.65 was employed to achieve a spatial resolution of about 1 μ m. Fig. 1(b) shows the fluorescence mapping of a 920 μ m diameter Cr:YAG fiber, which was used as a calibration standard for the $\rm Cr^{3+}$ concentration from fluorescence measurements.

3. Results

3.1. Cr_{oct}^{3+} and Cr_{tetr}^{4+} fluorescence spectra

The emissions from Cr_{oct}^{3+} and Cr_{tetr}^{4+} are in the visible and NIR, respectively. With confocal fluorescence microscopy they can be distinguished with micron-level spatial resolution. Fig. 2(a) shows



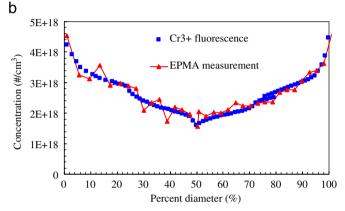


Fig. 1. (a) EPMA measured dopant profiles of a $70\,\mu m$ Ca,Cr:YAG fiber. (b) Quantitative comparison between the LSCM and EPMA measurements.

the Cr_{oct}^{3+} reflection fluorescence intensities showing the typical Cr_{oct}^{3+} emission spectra from a sharp R-line (689 nm from $^2E \rightarrow ^4A_2$ transition) [20–23] associated with three phonon sidebands (675, 707, and 726 nm). It was observed that the Cr_{oct}^{3+} fluorescence intensity increases after oxygen annealing. The corresponding Cr_{tetr}^{4+} fluorescence spectra are shown in Fig. 2(b). These spectra show the representative broadband emission from 1.2 to 1.6 μ m resulting from the $^3T_2 \rightarrow ^3A_2$ transition. The central wavelength is at 1.38 μ m with a 3 dB bandwidth of 265 nm. The Cr_{tetr}^{4+} spectral density of the as-grown samples also increases with oxygen annealing.

3.2. The influence of nitrogen and oxygen annealing treatments

The Ca,Cr:YAG and Mg,Ca,Cr:YAG single-crystal fibers were annealed in a nitrogen or oxygen atmosphere at different temperatures and then the fluorescence intensities of Cr_{oct}³⁺ and Cr_{tetr}^{4+} were measured. In Figs. 3(a) and 4(a), a critical temperature can be seen at about 700 °C. With oxygen annealing, chromium migration takes place from the octahedral site to the tetrahedral site at higher temperatures, which promotes the Cr⁴⁺_{tetr} fluorescence intensity. The chromium migration proceeds in the opposite direction with nitrogen annealing, $Cr_{tetr}^{4+} \rightarrow Cr_{oct}^{4+}[15-17]$, which decreases the Cr⁴⁺_{tetr} fluorescence intensity. In contrast to Cr⁴⁺_{tetr}, the fluorescence intensity of Cr_{oct}^{3+} , as shown in Figs. 3(b) and 4(b), is greater with a nitrogen atmosphere than with an oxygen atmosphere. This is due to more Cr_{oct} ions being transformed into Cr⁴⁺ ions with oxygen annealing. The Cr_{oct} is partially oxidized during fiber growth, and is stabilized as Cr_{tetr} in a distorted tetrahedral coordination. When the annealing temperature increases from 25 to 700 °C, the Cr⁴⁺_{tetr} fluorescence intensity

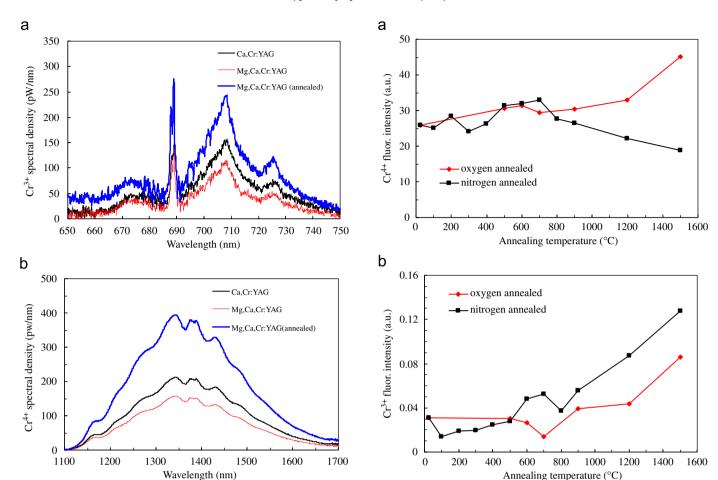


Fig. 2. The reflected fluorescent spectra of (a) Cr_{oct}^{3+} and (b) Cr_{tetr}^{4+} from Ca,Cr:YAG, and Mg,Ca,Cr:YAG as-grown samples, and Mg,Ca,Cr:YAG after oxygen annealing at 1350 °C.

Fig. 3. (a) Cr_{tetr}^{4+} and (b) Cr_{oct}^{3+} fluorescence intensities for Ca,Cr:YAG single-crystal fibers with nitrogen and oxygen annealing.

increases slightly with the nitrogen and oxygen annealing as shown in Figs. 3(a) and 4(a). As depicted in Figs. 3(b) and Fig. 4(b), there are many C_{oct}^{3+} ions doped into distorted octahedral sites.

The experimental result can be summarized as follows. There are two major conditions that affect the fluorescence intensity: one is the lattice quality of the Cr:YAG crystal, which depends on the annealing temperature; the other is the basic reaction of the Cr valence change. The greater the concentration of divalent codoped ions the greater is the distortion of the lattice coordination. The Cr⁴⁺_{cct} and Cr³⁺_{oct} fluorescence intensities of the Mg,Ca,Cr:YAG samples were lower than that of the Ca,Cr:YAG sample at 25 °C because of the increased number of defects. With a higher annealing temperature, the lattice quality and redox equilibrium changes significantly between 700 and 1500 °C. At an annealing temperature of 1500 °C, we obtained the highest fluorescence efficiency. So the following concentration analyses were performed at this annealing temperature.

4. Discussion and analysis

4.1. Analysis of chromium ion states and the relative stabilizing energy

YAG has a cubic crystal structure (space group Ia3d) with eight formula units per unit cell. The 24 Y atoms of the unit cell are surrounded by a dodecahedron of O atoms, while 16 (40%) of

the Al atoms are surrounded by oxygen octahedra and 24 (60%) of the Al atoms are surrounded by oxygen tetrahedra [10]. Assuming that no ions occupy interstitial lattice positions when divalent metal oxides are doped into the YAG matrix, the following formula satisfies charge neutrality [13]:

$$2\text{MeO} + 2X^{3+} + O^{2-} \leftrightarrow 2\text{Me}^{2+} + V_0^{2+} + X_2O_3. \tag{1}$$

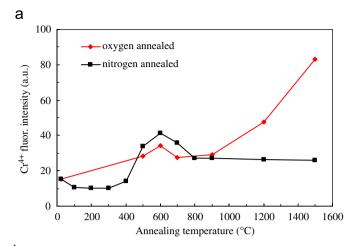
 Al^{3+} and Y^{3+} ions are denoted as X^{3+} , the oxygen vacancy is denoted as V_0^{2+} , Ca and Mg are denoted as Me.

The chromium ions in the YAG crystal substitute aluminum ions and normally occupy octahedral sites, giving $Cr_{\rm oct}^{3+}$ emission [11]. The $Cr_{\rm oct}^{3+}$ can change its oxidation state to 4 with the help of Me ions, which serve as charge compensators as shown below [11,13,24]:

$$Cr_{oct}^{3+} + \frac{1}{2}(V_0^{2+} + 2Me^{2+}) + \frac{1}{4}O_2 \leftrightarrow (Cr_{oct}^{4+} + Me^{2+}).$$
 (2)

The oxygen vacancies exist in co-doped garnet as complexes $(V_0^{2+}+2Me^{2+})$.

During annealing, oxygen vacancies diffuse and recombine with atmospheric oxygen at the surface of the crystal fiber. A positive charge thus released is transported by the hole to the crystal's volume, located on a $Cr_{\rm oct}^{3+}$ in an octahedral site and a $Cr_{\rm oct}^{4+}$ ion is formed. For the reverse direction of the equation, the positive charge is transported from the $Cr_{\rm oct}^{4+}$ ion to the crystal's surface and the opposite conversion takes place [17]. At high temperatures, the chromium ions migrate toward the tetrahedral



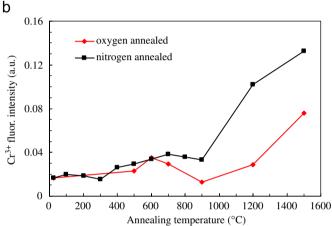


Fig. 4. (a) Ct_{roct}^{4+} and (b) Ct_{roct}^{3+} fluorescence intensities for Mg,Ca,Cr:YAG single-crystal fibers with nitrogen and oxygen annealing.

sites and the reaction is [17,24]

$$Cr_{oct}^{4+} + Al_{tetr}^{3+} \leftrightarrow Cr_{tetr}^{4+} + Al_{oct}^{3+}$$
 (3)

Application of the mass action law to reaction (3) leads to the relationship [17,25]

$$\frac{[Cr_{\text{tetT}}^{4+}]}{[Cr_{\text{oct}}^{4+}]} = K_0 e^{-E_{\text{CrAI}}/k_B T}. \tag{4}$$

The relative stabilization energy of the reaction is $E_{\rm CrAl}$. $k_{\rm B}$ is Boltzman's constant. T is the temperature (in Kelvin). Bracketed species stand for the appropriate ion concentration. The equations above are the basic reactions in the co-doped YAG. According to Eqs. (1) and (2), the incorporated divalent ions generates oxygen voids, and some of the oxygen voids react with ${\rm Cr}_{\rm oct}^{3+}$ to produce ${\rm Cr}^{4+}$. This can be quantified as

$$2[Me^{2+}] = [V_0^{2+}] + 2[Cr_{oct}^{4+}] + 2[Cr_{tetr}^{4+}].$$
(5)

Firstly, the mole percentage of the divalent ions to that of Cr is less than 2.5 in this work, and the Cr^{4+}_{tetr} fluorescence intensity is greatly increased after oxygen annealing. Secondly, the radius of Cr^{4+}_{tetr} is about 55 pm, which is much smaller than that of $Cr^{6+}_{tetr}(69 \, \text{pm})$. Therefore, it is reasonable to expect negligible quantities of Cr^{6+}_{tetr} [10,19,24]. Our defect study on the Cr:YAG crystal fibers has shown that the defect densities are usually very low, i.e. less than $2.6 \times 10^{-6} \, \text{\#/cm}^2$. Therefore, interstitial defects can be neglected in our samples, and the conservation of

chromium ions can be expressed as

$$[Cr] = [Cr_{oct}^{3+}] + [Cr_{oct}^{4+}] + [Cr_{tetr}^{4+}].$$
(6)

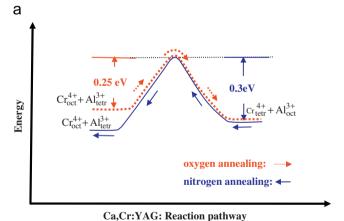
The concentrations of Cr, Ca^{2+} , and Mg^{2+} were measured by EPMA. Cr_{oct}^{3+} and Cr_{tetr}^{4+} were derived from the fluorescence measurements. Combining Eqs. (4–6), the concentrations of Cr_{oct}^{4+} , non-reacted V_{o}^{2+} , and the relative stabilization energy E_{CrAl} were obtained.

As mentioned earlier, we analyzed the experimental data at 1500 °C. The measured Cr_{oct}^{3+} fluorescence intensity with oxygen annealing at 1500 °C was calibrated by an EPMA measurement. The Cr_{tetr}^{4+} fluorescence intensity was calibrated by its absorption coefficient and compared with the results of Sugimoto and Borodin [11,26] to estimate the Cr_{tetr}^{4+} concentration. The Cr_{tetr}^{4+} fluorescence intensity has been converted into the Cr_{tetr}^{4+} concentration by adopting the absorption cross-section of $5 \times 10^{-18} \, \text{cm}^2$ [18]. Lipavsky et al. [27] showed that there is no significant impact of the co-dopants (Mg^{2+} or Ca^{2+}) on the optical absorption of the

Table 1 The ratio of the concentrations of divalent dopant (Me), Cr_{oct}^{3+} , Cr_{oct}^{4+} , Cr_{oct}^{4+} , ions to the total Cr ions, and the relative stabilizing energy (E_{CrAl}) for Ca,Cr:YAG (sample \$1) and Mg,Ca,Cr:YAG (sample \$2) single-crystal fibers

Sample no.	Annealing environment	Me/Cr (%)	Cr _{oct} /Cr (%)	Cr _{oct} /Cr (%)	Cr ⁴⁺ _{tetr} /Cr (%)	E _{CrAl} (eV)
1	02	113.1	57.8	39.4	2.8	0.25
1	N_2	113.1	85.5	13.3	1.2	0.30
2	02	252.3	48.9	46.1	5.0	0.47
2	N ₂	252.3	85.2	13.2	1.6	0.49

The annealing temperature was 1500 °C at 1 atm.



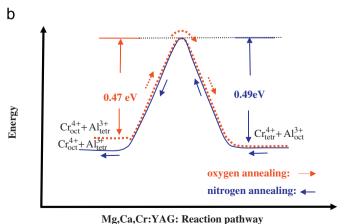


Fig. 5. The relative stabiliziation energies of (a) Ca,Cr:YAG, and (b) Mg,Ca,Cr:YAG single-crystal fibers with oxygen and nitrogen annealing.

Table 2
The percentages of Cr_{tetr}^{4+} and Cr_{oct}^{4+} relative to the divalent dopants and total Cr ions, and the percentage of non-reaction oxygen vacancies relative to the total oxygen vacancies

Sample no.	Annealing environment	$Cr_{tetr}^{4+}/Mg^{2+} + Ca^{2+}$ (%)	$Cr_{oct}^{4+}/Mg^{2+} + Ca^{2+}$ (%)	Non-reaction V _o ²⁺ /total V _o ²⁺ (%)	$Cr_{tetr}^{4+} + Cr_{oct}^{4+} + Cr$ (%)
1	02	2.5	34.8	62.7	42.2
1	N_2	1.0	11.8	87.2	14.5
2	O_2	2.0	18.2	79.8	51.5
2	N_2	0.6	5.2	94.2	14.8

 Cr^{4+} ion in YAG, at least at 1064 nm. Therefore, the Cr_{oct}^{3+} concentrations of Ca,Cr:YAG samples with oxygen and nitrogen annealing at $1500\,^{\circ}\text{C}$ were determined to be $8.58\times10^{^{18}}$ and $1.27 \times 10^{19} \, \text{\#/cm}^3$, respectively. Similarly in the Mg,Ca,Cr:YAG samples, they were 7.58×10^{18} and $1.32 \times 10^{19} \, \text{\#/cm}^3$, respectively. The Cr_{tetr} concentration in the Ca,Cr:YAG samples in oxygen and nitrogen at 1500 °C were 4.17×10^{17} and 1.75×10^{17} #/cm³, and they were 7.68×10^{17} and 2.4×10^{17} #/cm³ in the Mg,Ca,Cr:YAG samples. Table 1 summarizes the results of annealing at 1500 °C. For sample \$1, i.e. the Ca,Cr:YAG crystal, with oxygen annealing, the ratios of Cr_{oct}^{3+}/Cr , Cr_{oct}^{4+}/Cr , and Cr_{tetr}^{4+}/Cr were 57.8%, 39.4%, and 2.8%, respectively. In view of Fig. 3, the evolution of the Cr valence and migration follow the path $Cr_{oct}^{3+} \rightarrow Cr_{oct}^{4+} \rightarrow Cr_{tetr}^{4+}$. In contrast, with nitrogen annealing, the evolution of the Cr valence and migration follows a reverse path, i.e. $Cr_{tetr}^{4+} \rightarrow Cr_{oct}^{4+} \rightarrow Cr_{oct}^{3+}$. There were similar results for sample #2. It was observed that the higher the concentration of divalent dopant ions, the larger the percentage of Cr_{tetr}⁴⁺ arising with oxygen annealing.

The relative stabilization energy $E_{\rm CrAl}$ in Table 1 was estimated using Eq. (4). For sample \$1, $E_{\rm CrAl}$ with oxygen annealing was about 0.25 eV, while with nitrogen annealing it was about 0.30 eV. For sample \$2, these values were 0.47 and 0.49 eV for oxygen and nitrogen annealing, respectively. The reaction pathway can be depicted using Fig. 5. With either annealing, the Mg,Ca,Cr:YAG crystal fiber has a higher relative stabilization energy than the Ca,Cr:YAG crystal fiber. A probable reason is that there is a large misfit produced by the Mg²⁺ in replacing the octahedral Al³⁺ site, which causes excessive distortion in the YAG matrix. So the octahedrons were enlarged, thus increasing the stress, which, as a consequence, increases the relative stabilization energy.

4.2. Reduced charge compensation efficiency due to oxygen vacancies

As shown in Eqs. (1) and (2), the doped divalent ions promote charge compensation as well as oxygen vacancies. The latter reduces the charge compensation efficiency. Based on the analysis in Section 4.1, the percentages of Cr_{tetr}⁴⁺ and Cr_{oct}⁴⁺ to total Cr, and the percentage of un-reacted oxygen vacancies to the total oxygen vacancies are summarized in Table 2. For either oxygen or nitrogen annealing, less than 3% of the divalent dopant ions became active for charge compensation and produce Cr_{tetr} for NIR emission. For the Ca,Cr:YAG crystal fiber, there were 34.8% and 2.5% of Ca²⁺ ions available to charge compensate and produce Cr⁴⁺ in octahedral and tetrahedral sites with oxygen annealing. In the nitrogen atmosphere, only 11.8% and 1% of Ca²⁺ were active. For the Mg,Ca,Cr:YAG crystal fiber, charge compensation for the divalent dopant ions was lower than that for the Ca,Cr:YAG crystal, but charge compensation for the Cr ions was higher. The ratio of un-reacted oxygen vacancies to the total oxygen vacancies was about 63% and 87% with oxygen and nitrogen annealing of the Ca,Cr:YAG crystal fiber. These values were 80% and 94% for the Mg,Ca,Cr:YAG crystal fiber. This result shows that the low charge

compensation efficiency is mainly due to the existence of oxygen vacancies in the YAG matrix. The majority of the generated oxygen vacancies remained un-reacted.

5. Conclusion

The oxidation states of Cr ions in Cr:YAG crystal fibers codoped with divalent ions have been studied quantitatively. There are two conditions that affect the chromium valence change in the YAG crystal fiber. One is the electronic charging and recharging process, $Cr_{oct}^{4+} \leftrightarrow Cr_{oct}^{3+}$, which depends on temperature, the concentration of divalent ions, the ambient atmosphere and the number of oxygen vacancies. The other is the chromium migration process, $Cr_{tetr}^{4+} \leftrightarrow Cr_{oct}^{4+}$, which depends on the annealing temperature. The relative stabilization energy of Cr ions between octahedral and tetrahedral sites is analyzed. The YAG fibers with Mg²⁺ doping showed higher relative stabilization energy than those with Ca^{2+} . Oxygen annealing facilitates the $Cr_{oct}^{3+} \rightarrow Cr_{oct}^{4+} \rightarrow$ Cr_{tetr} charge compensation and migration path. The migration of Cr_{oct} in the YAG lattice to Cr_{tetr} takes place above 700 °C. Oxygen vacancies are the major cause of the reduced charge compensation efficiency. For the Ca,Cr:YAG sample, up to 37.3% of the divalent ions compensated the Cr³⁺ to Cr⁴⁺, though only 2.5% was active in fluorescence. For the Mg,Ca,Cr:YAG crystal fiber, less than 2% of the divalent ions became active for charge compensation to Cr_{tetr}^{4+} . The ratio between un-reacted and total oxygen vacancies in the Ca,Cr:YAG fiber is smaller than that of the Mg,Ca,Cr:YAG fiber. The majority of the oxygen vacancies were un-reacted, which is the main reason why Cr_{tetr} concentrations are usually limited to less than 5% of the total Cr ions.

Acknowledgments

The authors are grateful to Mr. B. Chiang for composition analysis using EPMA. The authors also gratefully acknowledge the support of this research by the Ministry of Education Program for Promoting Academic Excellence of Universities under grant number 91-E-FA08-1-4.

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